	Application No.	Applicant(s)
Notice of Allowability	10/645,646	
	Examiner -	COHEN, GUY MOSHE Art Unit
	Thanhha Pham	
	Thannna Pham	2813
The MAILING DATE of this communication app All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT R of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in the community of	this application. If not included
1. This communication is responsive to 10/4/07 and interview	v dated 12/20/07.	
2. X The allowed claim(s) is/are 1-6, 8-11, 21-24, 28-38 and 41	-43 .	
 3. Acknowledgment is made of a claim for foreign priority unally all blacks and blacks are supported by the control of the control of the control of the control of the priority documents have a control of the control of the priority documents have a control of the control of the priority documents have a control of the control of the priority documents have a control of the control of the priority documents have a control of the priority documents. 	e been received. e been received in Application	No
International Bureau (PCT Rule 17.2(a)).	•	- · · · · · · · · · · · · · · · · · · ·
* Certified copies not received:		
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONN THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.	of this communication to file a IENT of this application.	reply complying with the requirements
4. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which give	nitted. Note the attached EXAN es reason(s) why the oath or c	MINER'S AMENDMENT or NOTICE OF declaration is deficient.
5. CORRECTED DRAWINGS (as "replacement sheets") mus	st be submitted.	
(a) I including changes required by the Notice of Draftspers		(PTO-948) attached
1) 🗌 hereto or 2) 🔲 to Paper No./Mail Date	•	
(b) ☐ including changes required by the attached Examiner's Paper No./Mail Date	s Amendment / Comment or in	the Office action of
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t	.84(c)) should be written on the header according to 37 CFR	drawings in the front (not the back) of 1.121(d).
 DEPOSIT OF and/or INFORMATION about the depo attached Examiner's comment regarding REQUIREMENT 	SIT OF BIOLOGICAL MATER FOR THE DEPOSIT OF BIOL	RIAL must be submitted. Note the OGICAL MATERIAL.
Attachment(s) . 1. ☐ Notice of References Cited (PTO-892)	5 - Notice of Infa	rmal Patent Application
2. ☐ Notice of Preferences Cited (F10-092) 2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948)	6. ☐ Interview Sun	
	Paper No./M	ail Date mendment/Comment
 Information Disclosure Statements (PTO/SB/08), Paper No./Mail Date <u>12/18/07</u> 	7. 🔀 Examiner's A	mendment/Comment
Examiner's Comment Regarding Requirement for Deposit of Biological Material	8. 🔀 Examiner's Si	atement of Reasons for Allowance
	9.	
	TH PRII	ANHHA S. PHAM MARY EXAMINER

EXAMINER'S AMENDMENT

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Scott Tulino on 12/20/07.

The application has been amended as follows:

In claim 11,

Line 1, change "7" to – 1 –

Line 1, change "further" to - wherein said strained-silicon channel -

Allowable Subject Matter

- 2. Claims 1-6, 8-11, 21-24, 28-38, 41-43 are allowed.
- 3. The following is an examiner's statement of reasons for allowance:
- Recorded Prior Art fails to disclose or suggest the semiconductor device or double-gate field effect transistor as characteristics as cited in base claims 1, 21, 30 and 31 comprising: a strained-silicon channel formed adjacent a source and a drain on a substrate, said strained-silicon channel comprising two separated portions, wherein each of said two separated portions of said strained-silicon channel connects said source and said drain; a first gate formed over a first vertical outer side of said strained-silicon channel; a second gate formed over a second vertical inner side of said strained-

silicon channel located between said two separated portions of said strained-silicon channel; wherein said first gate comprises at least one chemical element not included in said second gate. said first gate dielectric is chemically different than said second gate dielectric.

4. Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thanhha Pham whose telephone number is (571) 272-1696. The examiner can normally be reached on Monday and Thursday 9:00AM - 9:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead Jr can be reached on (571) 272-1702. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic

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Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

TSP

THANHHA S. PHAM PRIMARY EXAMINER